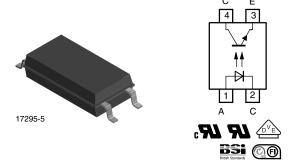




www.vishay.com

Vishay Semiconductors

Optocoupler, Phototransistor Output, SOP-4L, Long Mini-Flat Package



DESCRIPTION

The TCLT100. series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead SOP4L package.

APPLICATIONS

- Switchmode power supplies
- · Computer peripheral interface
- Microprocessor system interface

FEATURES

- SMD low profile 4 lead package
- V_{IORM} = 1050 V
- CTR flexibility available see order information
- Special construction
- · Extra low coupling capacitance
- DC input with transistor output
- Creepage distance > 8 mm
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ROHS COMPLIANT HALOGEN

FREE GREEN (5-2008)

AGENCY APPROVALS

- UL1577, file no. E76222
- CSA (cUL) 22.2 bulletin 5A recognized file no. E-76222
- BSI: BS EN 41003, BS EN 60065 (BS 415), BS EN 60950 (BS 7002), certificate number 7081 and 7402
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO: EN 60950
- CQC

Note

 See the safety standard approval list "Agency Table" for more detailed information.

ORDERING INFORMATION										
Т		L	Т	1	0	0	#		SOP-4L	h
	PART NUMBER 10.2 mm →							_		
AGENCY	AGENCY CTR (%)									
CERTIFIED/PACKAGE		5 mA		10 mA				5 mA		
UL, cUL, VDE, BSI, F	UL, cUL, VDE, BSI, FIMKO 50 to 600 63 to 125 100 to 200 160 to 320 50 to 150 100 to 300 80 to 160 130 to 260 200 to						200 to 400			
SOP-4L	•	TCLT1000	TCLT1002	TCLT1003	TCLT1004	TCLT1005	TCLT1006	TCLT1007	TCLT1008	TCLT1009

Note

· Available only on tape and reel.



TCLT100. Series

Vishay Semiconductors

PARAMETER	CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6	V
Forward current		I _F	60	mA
Forward surge current	t _p ≤ 10 μs	I _{FSM}	1.5	Α
Power dissipation		P _{diss}	100	mW
Junction temperature		Tj	125	°C
OUTPUT				
Collector emitter voltage		V _{CEO}	70	V
Emitter collector voltage		V _{ECO}	7	V
Collector current		Ic	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA
Power dissipation		P _{diss}	150	mW
Junction temperature		Tj	125	°C
COUPLER				
Total power dissipation		P _{tot}	250	mW
Operating ambient temperature range		T _{amb}	-55 to +100	°C
Storage temperature range		T _{stg}	-55 to +125	°C
Soldering temperature		T _{sld}	260	°C

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT									
Forward voltage	$I_F = 50 \text{ mA}$	V _F	-	1.25	1.6	V			
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C _j	-	50	-	pF			
OUTPUT									
Collector emitter voltage	$I_C = 1 \text{ mA}$	V_{CEO}	70	-	-	V			
Emitter collector voltage	I _E = 100 μA	V _{ECO}	7	-	-	V			
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}	-	10	100	nA			
COUPLER	COUPLER								
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	V _{CEsat}	-	-	0.3	V			
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f _c	-	110	-	kHz			
Coupling capacitance	f = 1 MHz	C _k	-	0.3	-	pF			

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.





CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	$V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$	TCLT1000	CTR	50	-	600	%	
		TCLT1002	CTR	63	-	125	%	
	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	TCLT1003	CTR	100	-	200	%	
l⊙/l _F		TCLT1004	CTR	160	-	320	%	
		TCLT1002	CTR	22	45	-	%	
	$V_{CE} = 5 \text{ V}, I_{F} = 1 \text{ mA}$	TCLT1003	CTR	34	70	-	%	
		TCLT1004	CTR	56	100	-	%	
		TCLT1005	CTR	50	-	150	%	
		TCLT1006	CTR	100	-	300	%	
	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	TCLT1007	CTR	80	-	160	%	
		TCLT1008	CTR	130	-	260	%	
		TCLT1009	CTR	200	-	400	%	

SAFETY AND INSULATION RATINGS							
PARAMETER	CONDITION	SYMBOL	VALUE	UNIT			
Partial discharge test voltage - routine test	100 %, t _{test} = 1 s	V_{pd}	2	kV			
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$	V _{IOTM}	8	kV _{peak}			
lot test (sample test)	(see figure 2)	V_{pd}	1.68	kV _{peak}			
Isolation test voltage (RMS)		V _{ISO}	5000	V_{RMS}			
	V _{IO} = 500 V	R _{IO}	10 ¹²	Ω			
Insulation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	10 ¹¹	Ω			
modiation registration	V _{IO} = 500 V, T _{amb} = 150 °C (construction test only)	R _{IO}	10 ⁹	Ω			
Forward current		I _{si}	130	mA			
Power dissipation		P _{so}	265	mW			
Rated impulse voltage		V _{IOTM}	8	kV			
Safety temperature		T _{si}	150	°C			
Comparative tracking index		CTI	175				
Clearance distance			8.0	mm			
Creepage distance			8.0	mm			
Insulation distance (internal)			0.40	mm			

Note

 According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

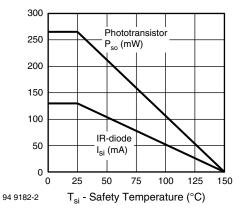


Fig. 1 - Derating Diagram

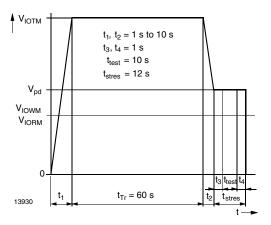


Fig. 2 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-2 (VDE 0884); IEC60747-5-5





SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Delay time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _d	-	3	-	μs		
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _r	-	3	-	μs		
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _f	-	4.7	-	μs		
Storage time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _s	-	0.3	-	μs		
Turn-on time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _{on}	-	6	-	μs		
Turn-off time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 3)	t _{off}	-	5	-	μs		
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 4)	t _{on}	-	9	-	μs		
Turn-off time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 4)	t _{off}	-	10	-	μs		

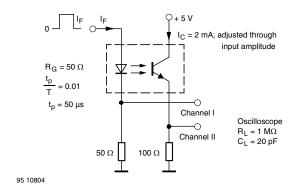


Fig. 3 - Test Circuit, Non-Saturated Operation

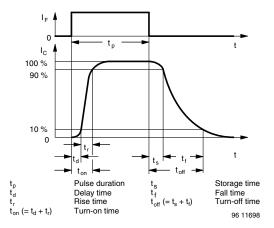


Fig. 5 - Switching Times

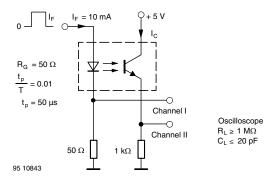


Fig. 4 - Test Circuit, Saturated Operation

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

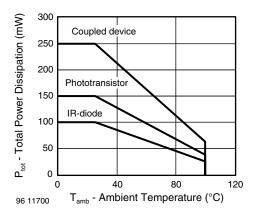


Fig. 6 - Total Power Dissipation vs. Ambient Temperature

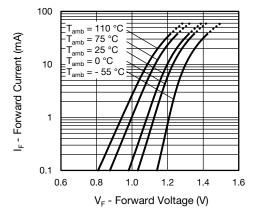


Fig. 7 - Forward Current vs. Forward Voltage

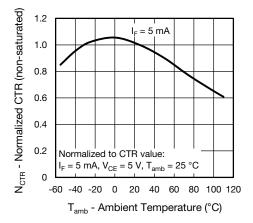


Fig. 8 - Normalized Current Transfer Ratio (non-saturated) vs.
Ambient Temperature

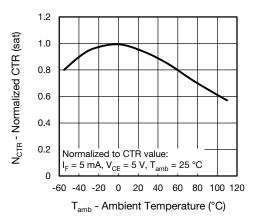


Fig. 9 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

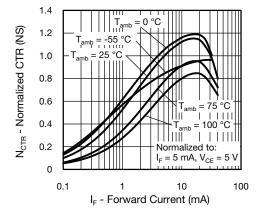


Fig. 10 - Normalized Current Transfer Ratio (non-saturated) vs. Forward Current

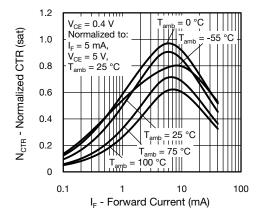


Fig. 11 - Normalized Current Transfer Ratio (saturated) vs. Forward Current



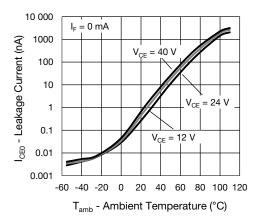


Fig. 12 - Collector Dark Current vs. Ambient Temperature

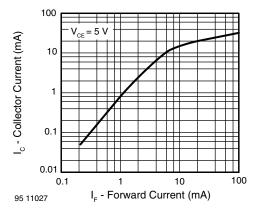


Fig. 13 - Collector Current vs. Forward Current

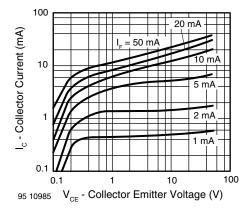


Fig. 14 - Collector Current vs. Collector Emitter Voltage

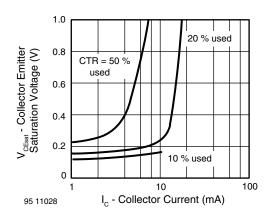


Fig. 15 - Collector Emitter Saturation Voltage vs. Collector Current

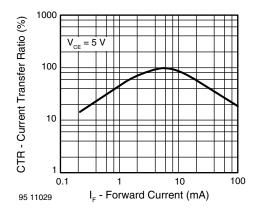


Fig. 16 - Current Transfer Ratio vs. Forward Current

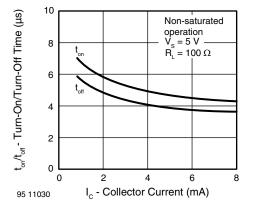


Fig. 17 - Turn-on/off Time vs. Collector Current



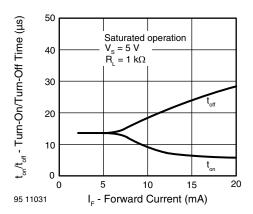
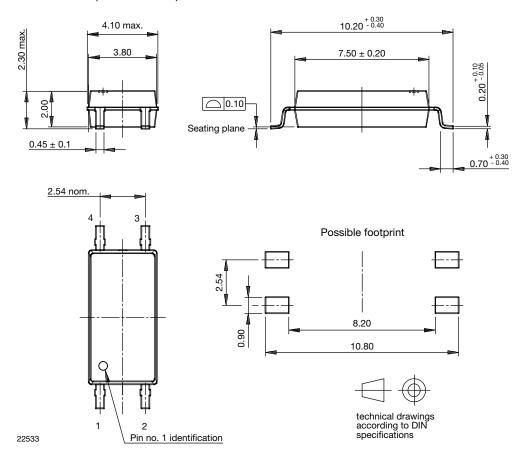
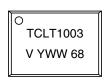


Fig. 18 - Turn-on/off Time vs. Forward Current

PACKAGE DIMENSIONS (in millimeters)



PACKAGE MARKING (example)





TAPE AND REEL DIMENSIONS (in millimeters)

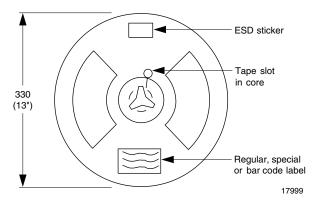


Fig. 19 - Reel Dimensions (3000 units per reel)

Direction of pulling out technical drawings according to Diring t

Fig. 20 - Tape Dimensions

SOLDER PROFILE

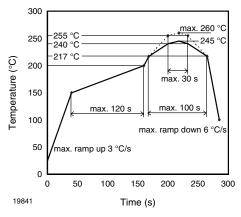


Fig. 21 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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Vishay

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